Quad. 2-input NAND Gates

# **HITACHI**

ADE-205-240 (Z) 1st Edition March 1999

#### **Description**

The HD74LV00A has four two-input NAND gates in a 14-pin package. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.3 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 6$  mA (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 12$  mA (@V<sub>CC</sub> = 4.5 V to 5.5 V)

#### **Function Table**

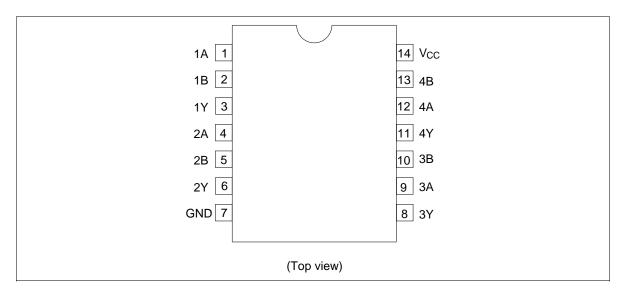
#### Inputs

A	В	Output Y
Н	Н	L
L	X	Н
X	L	Н

Note: H: High level
L: Low level
X: Immaterial



## **Pin Arrangement**



### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	$-0.5$ to $V_{cc}$ + 0.5	V	Output: H or L
		-0.5 to 7.0	-	V <sub>cc</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>1</sub> < 0
Output clamp current	I <sub>ok</sub>	±50	mA	$V_{o}$ < 0 or $V_{o}$ > $V_{cc}$
Continuous output current	Io	±25	mA	$V_{\rm O}$ = 0 to $V_{\rm CC}$
Continuous current through V <sub>cc</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*3	P <sub>T</sub>	785	mW	SOP
		500	-	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	2.0	5.5	V	
Input voltage range	V <sub>I</sub>	0	5.5	V	
Output voltage range	Vo	0	V <sub>cc</sub>	V	
Output current	I <sub>OH</sub>	_	-50	μΑ	V <sub>cc</sub> = 2.0 V
		_	-2	mA	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		_	-6	<del></del>	$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12	<del></del>	$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
	I <sub>OL</sub>	_	50	μΑ	V <sub>CC</sub> = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	6	<del></del>	$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12	<del></del>	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt /Δν	0	200	ns/V	$V_{cc} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100	<del></del>	$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

TTT	- 4-	T 7.0	
ши	7/1	1/4	
HD'	/ + 1 .	, V U	M

Logic Diagram

### **DC** Electrical Characteristics

#### • $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V <sub>cc</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_	<del></del>	
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_	_	
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_	_	
	V <sub>IL</sub>	2.0	_	_	0.5	_	
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$	_	
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$	_	
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	$V_{OH}$	Min to Max	V <sub>CC</sub> – 0.1	_	_	V	$I_{OH} = -50 \mu A$
		2.3	2.0	_	_	_	$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_	_	$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_	_	I <sub>OH</sub> = -12 mA
	V <sub>OL</sub>	Min to Max	_	_	0.1		$I_{OL} = 50 \mu\text{A}$
		2.3	_	_	0.4	_	I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44	_	I <sub>OL</sub> = 6 mA
		4.5	_	_	0.55	_	I <sub>OL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5			±1	μΑ	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>cc</sub>	5.5	_	_	20	μА	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	l <sub>OFF</sub>	0	_	_	5	μΑ	V <sub>O</sub> = 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	3.3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

## **Switching Characteristics**

•  $V_{CC} = 2.5 \pm 0.2 \text{ V}$ 

Ta = 25°C

Ta = -40 to85°C

Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	7.1	12.9	1.0	15.0	ns	C <sub>L</sub> = 15 pF	A or B	Υ
delay time	t <sub>PHL</sub>	_	9.6	16.6	1.0	20.0		C <sub>L</sub> = 50 pF		

•  $V_{CC} = 3.3 \pm 0.3 \text{ V}$ 

Ta = 25°C

Ta = -40 to

85°C

Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	5.0	7.9	1.0	9.5	ns	C <sub>L</sub> = 15 pF	A or B	Υ
delay time	t <sub>PHL</sub>	_	6.9	11.4	1.0	13.0		C <sub>L</sub> = 50 pF		

 $V_{\rm CC}$  = 5.0  $\pm$  0.5 V

Ta = 25°C

Ta = -40 to

					85°C					
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	3.6	5.5	1.0	6.5	ns	C <sub>L</sub> = 15 pF	A or B	Υ
delay time	t <sub>PHL</sub>	_	4.9	7.5	1.0	8.5		C <sub>L</sub> = 50 pF		

## **Operating Characteristics**

•  $C_L = 50 \text{ pF}$ 

Ta = 25°C

Item	Symbol	$V_{cc}$ (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Power dissipation capacitance	$C_{\mathtt{PD}}$	3.3	_	9.5	_	pF	f = 10 MHz
		5.0	_	11.0	_		

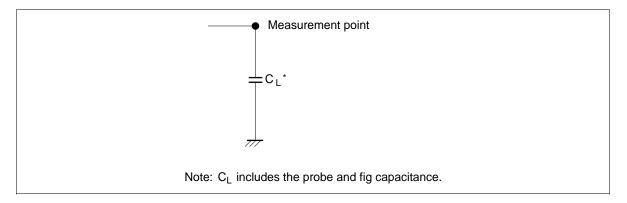
### **Noise Characteristics**

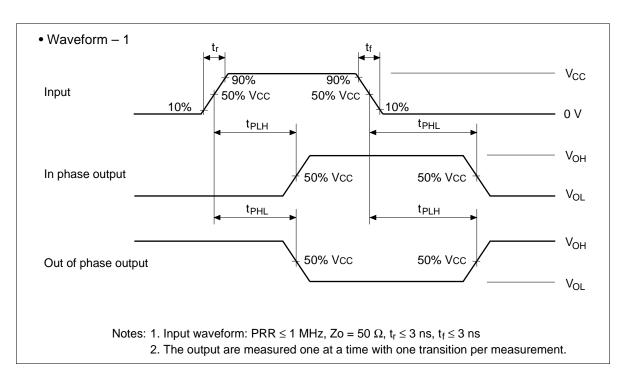
•  $C_L = 50 pF$ 

Ta = 25°C

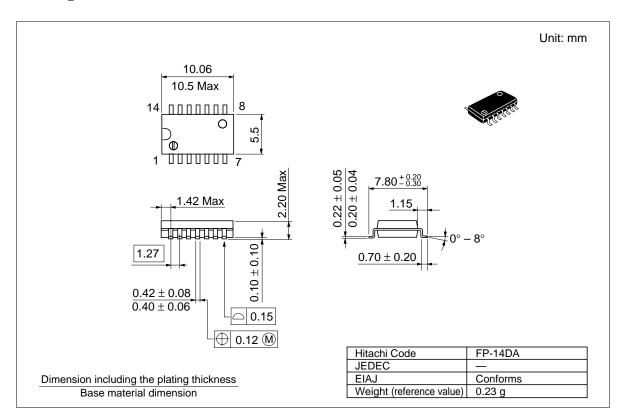
Item	Symbol	$V_{cc}$ (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Quiet output, maximum dynamic V <sub>OL</sub>	$V_{OL(P)}$	3.3	_	0.2	0.8	V	
Quiet output, minimum dynamic V <sub>OL</sub>	V <sub>OL (V)</sub>	3.3	_	-0.1	-0.8		
Quiet output, minimum dynamic V <sub>OH</sub>	V <sub>OH (V)</sub>	3.3	_	3.1	_		
High-level dynamic input voltage	V <sub>IH (D)</sub>	3.3	2.31	_	_	V	
Low-level dynamic inout voltage	V <sub>IL (D)</sub>	3.3	_	_	0.99		

#### **Test Circuit**

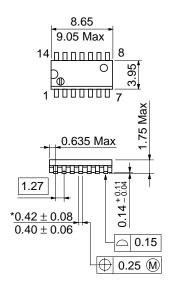




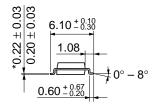
### **Package Dimensions**





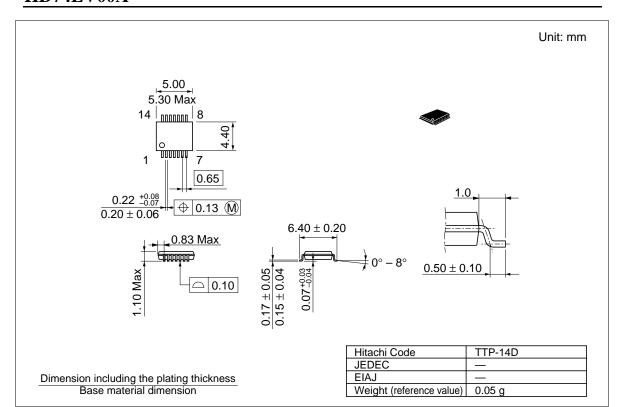






\*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g



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